

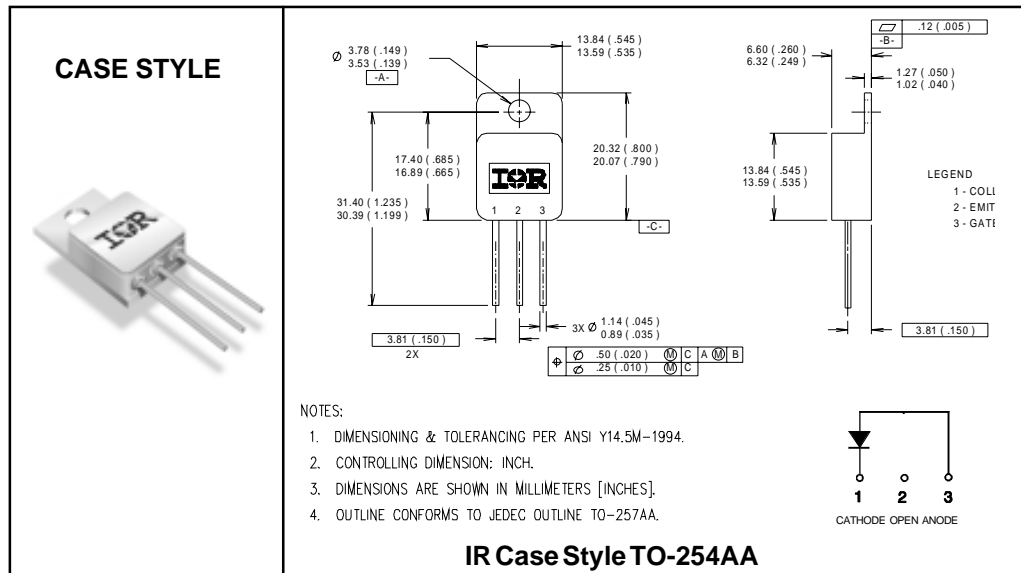
Major Ratings and Characteristics

Characteristics	35SGQ030	Units
$I_{F(AV)}$	35	A
V_{RRM}	30	V
I_{FSM} @ $t_p = 8.3ms$ half-sine	300	A
V_F @ 35Apk, $T_J = 125^\circ C$	0.69	V
T_J, T_{stg} Operating and storage	-55 to 150	$^\circ C$

Description/Features

The 35SGQ030 Schottky rectifier has been expressly designed to meet the rigorous requirements of hi-rel environments. It is packaged in the hermetic isolated TO-254AA package. The device's forward voltage drop and reverse leakage current are optimized for the lowest power loss and the highest circuit efficiency for typical high frequency switching power supplies and resonant power converters. Full MIL-PRF-19500 quality conformance testing is available on source control drawings to TX, TXV and S quality levels.

- Hermetically Sealed
- Low Forward Voltage Drop
- High Frequency Operation
- Guard Ring for Enhanced Ruggedness and Long term Reliability
- Lightweight



Voltage Ratings

Part number	35SGQ030
V _R Max. DC Reverse Voltage (V)	30
V _{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	Limits	Units	Conditions
I _{F(AV)} Max. Average Forward Current See Fig. 5	35	A	50% duty cycle @ T _C = 100°C, square waveform
I _{FSM} Max. Peak One Cycle Non - Repetitive Surge Current	300	A	@ t _p = 8.3 ms half-sine

Electrical Specifications

Parameters	Limits	Units	Conditions
V _{FM} Max. Forward Voltage Drop See Fig. 1①	0.76	V	@ 30A
	0.8	V	@ 35A
	1.05	V	@ 70A
	0.65	V	@ 30A
	0.70	V	@ 35A
	1.03	V	@ 70A
	0.62	V	@ 30A
	0.69	V	@ 35A
I _{RM} Max. Reverse Leakage Current See Fig. 2①	1.0	mA	T _J = 25°C
	76	mA	T _J = 100°C
	300	mA	T _J = 125°C
			V _R = rated V _R ②
C _T Max. Junction Capacitance	3700	pF	V _R = 5V _{DC} (1MHz, 25°C) ②
L _S Typical Series Inductance	7.8	nH	Measured from anode lead to cathode lead 6mm (0.025 in.) from package

Thermal-Mechanical Specifications

Parameters	Limits	Units	Conditions
T _J Max. Junction Temperature Range	-55 to 150	°C	
T _{stg} Max. Storage Temperature Range	-55 to 150	°C	
R _{thJC} Max. Thermal Resistance, Junction to Case	1.1	°C/W	DC operation See Fig. 4
wt Weight (Typical)	9.3	g	
Die Size (Typical)	200X200	mils	
Case Style	TO-254AA		

① Pulse Width < 300μs, Duty Cycle < 2%

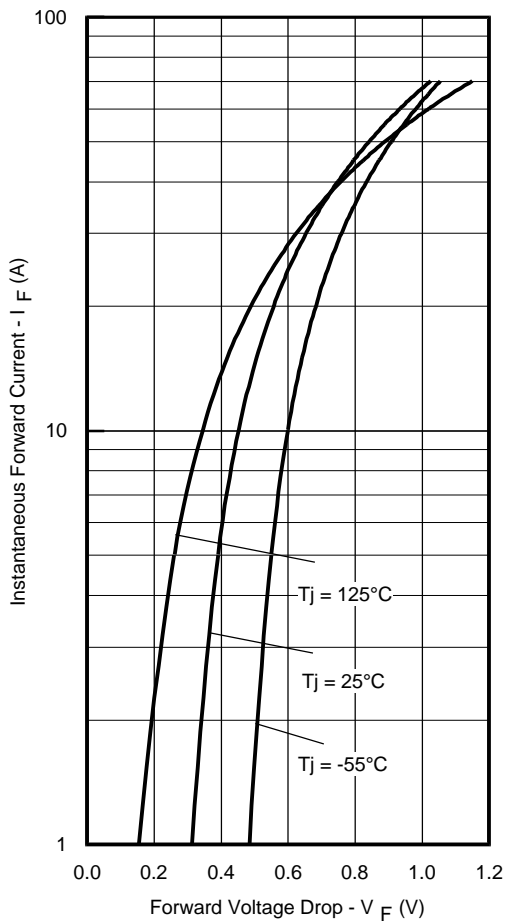


Fig. 1 - Max. Forward Voltage Drop Characteristics

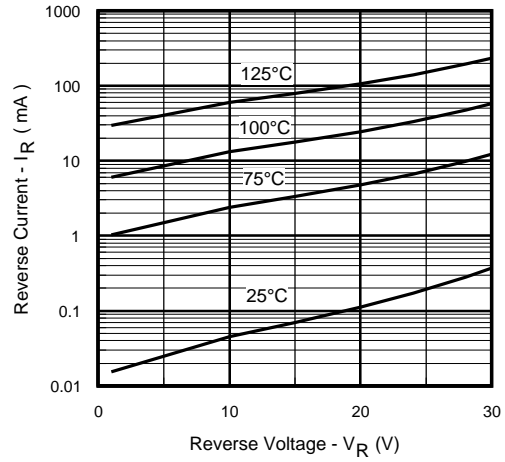


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

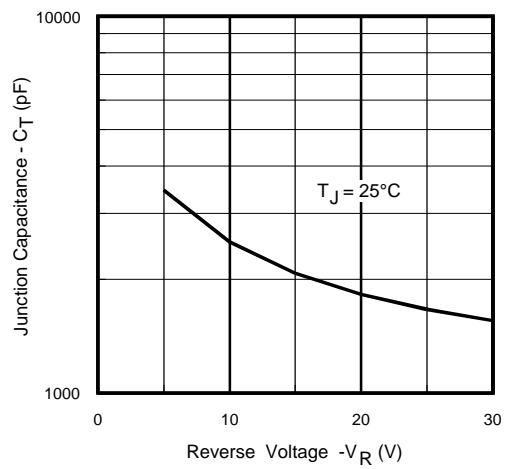


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

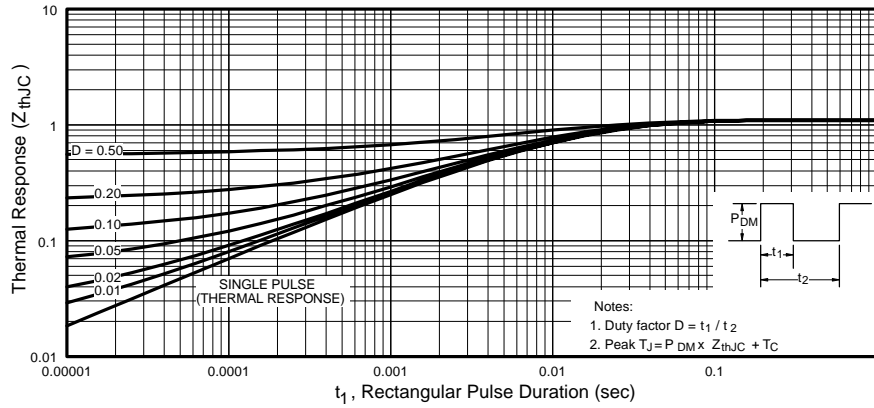


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

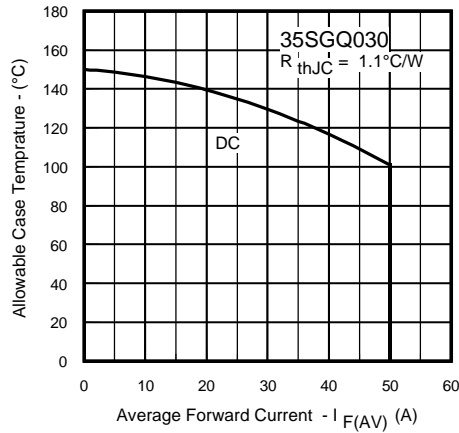


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

单击下面可查看定价，库存，交付和生命周期等信息

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